TOSHIBA Photocoupler IRLED & Photo-Transistor

TLX9291A

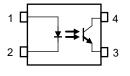
- Various Controllers
- Signal transmission between different circuit potential
- HEV (Hybrid Electric Vehicle) and
 - EV (Electric Vehicle) Applications

The TOSHIBA TLX9291A mini-flat photocoupler is suitable for surface-mount assembly. The TLX9291A consists of an infrared LED optically coupled to a photo-transistor.

This photocoupler can be used to the extensive applications.

- It is generic speed transistor output.
- Collector-emitter voltage: 80 V (min)
- Current transfer ratio: 50 % (min) to 600 %(max) Rank GB: 100 % (min) to 600 %(max)
- Isolation voltage: 3750 Vrms (min)
- AEC-Q101 qualified

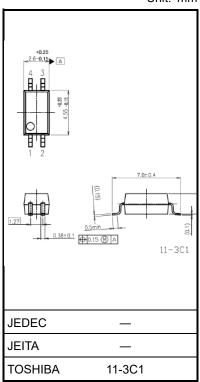
Pin Configuration



1: Anode 2: Cathode

3: Emitter

4: Collector



Weight: 0.05 g (typ.)

Absolute Maximum Ratings	(Note) (Unless otherwis	se specified, Ta = 25°C)
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	Characteristic		Symbol	Rating	Unit
	Forward current		lF	30	mA
	Forward current (Ta=125°C)		lF	18	mA
	Forward current derating (Ta ≥ 108 °C)			-0.7	mA/°C
LED	Pulse forward current	(Note 1)	IFP	1	А
	Input Power Dissipation		PD	50	mW
	Input Power Dissipation Derating (Ta ≥ 50°C)		∆PD/°C	-0.5	mW/°C
	Reverse voltage		VR	5	V
	Collector-emitter voltage		VCEO	80	V
r	Emitter-collector voltage		V _{ECO}	7	V
Detector	Collector current		Ic	50	mA
ð	Collector power dissipation		Pc	150	mW
	Collector power dissipation derating (Ta \ge 50°C)		ΔP _C /°C	-1.5	mW/°C
Оре	erating temperature range		T _{opr}	-40 to 125	°C
Storage temperature range			T _{stg}	-55 to 150	°C
Lead soldering temperature (10s)			T _{sol}	260	°C
Total package power dissipation			PT	200	mW
Tota	al package power dissipation derating (Ta \ge 50°C)		ΔP _T /°C	-2.0	mW/°C
Isol	ation voltage (AC, 60 s, R.H. ≤ 60 %)	(Note 2)	BVs	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width PW \leq 100 µs, 100 Hz

Note 2: This device is considered as a two terminal device: Pins 1 and 2 are shorted together, and pins 3 and 4 are shorted together.

Recommended Operating Conditions (Note)

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	Vcc	_	5	48	V
Forward current	lF	_	10	15	mA
Collector current	lc		1	10	mA
Operating temperature (Note 1)	Topr	-40	_	125	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 1: Denotes the operating range, not the recommended operating condition.

Electrical Characteristics (Unless otherwise specified, Ta = -40 to 125°C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	E-mail and the sec		I _F = 10 mA, Ta=25 °C	1.1	1.27	1.4	V
Q	Forward voltage	VF	IF = 10 mA	1.0	_	1.55	V
LED	Reverse current	IR	V _R = 5 V	-		10	μA
	Capacitance	Ст	V = 0 V, f = 1 MHz, Ta=25 °C	_	35	_	pF
	Collector-emitter breakdown voltage	V(BR)CEO	IC = 0.5 mA	80	_	Ι	V
or	Emitter-collector breakdown voltage	V(BR)ECO	IE = 0.1 mA	7	_	_	V
Detector			V _{CE} = 48 V, Ta=25 °C	_	10	100	nA
ă	Collector dark current	ICEO	V _{CE} = 48 V, Ta=105 °C	_	5	50	μA
			V _{CE} = 48 V, Ta=125 °C	_	30	100	μA
	Capacitance (collector to emitter)	C _{CE}	V = 0 V, f = 1 MHz, Ta=25 °C	_	10	_	pF

Coupled Electrical Characteristics (Unless otherwise specified, Ta = -40 to 125°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
		I _F = 5 mA, V _{CE} = 5 V	20	_	600	%
Current transfer ratio	IC/IF	I _F = 5 mA, V _{CE} = 5 V, Ta=25 °C	50	_	600	
	IC/IF	I _F = 5 mA, V _{CE} = 5 V , Ta=25 °C Rank GB	100	_	600	
	IC/IF(sat)	I _F = 1 mA, V _{CE} = 0.4 V, Ta=25 °C	_	200	_	%
Saturated CTR		I _F = 1 mA, V _{CE} = 0.4 V, Ta=25 °C Rank GB	30	-	_	
	VCE(sat)	IC = 2.4 mA, IF = 8 mA, Ta=25 °C			0.4	
Collector-emitter saturation voltage		I _C = 0.2 mA, I _F = 1 mA			0.4	V
		Ta=25 °C	_	0.1	0.4	
Off-state collector current	IC(off)	V _F = 0.7 V, V _{CE} = 48 V , Ta=25 °C	_	_	10	μA

Isolation Characteristics (Ta = 25°C)

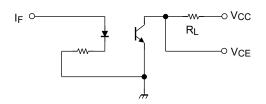
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input to output)	Cs	V _S = 0 V, f = 1 MHz	_	0.5	_	pF
Isolation resistance	Rs	V _S = 500 V, R.H. ≤ 60 %	5×10 ¹⁰	10 ¹⁴	_	Ω
Isolation voltage	BVs	AC, 60 s	3750	_		Vrms

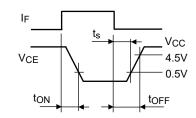
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Switching Characteristics (Ta = 25°C)

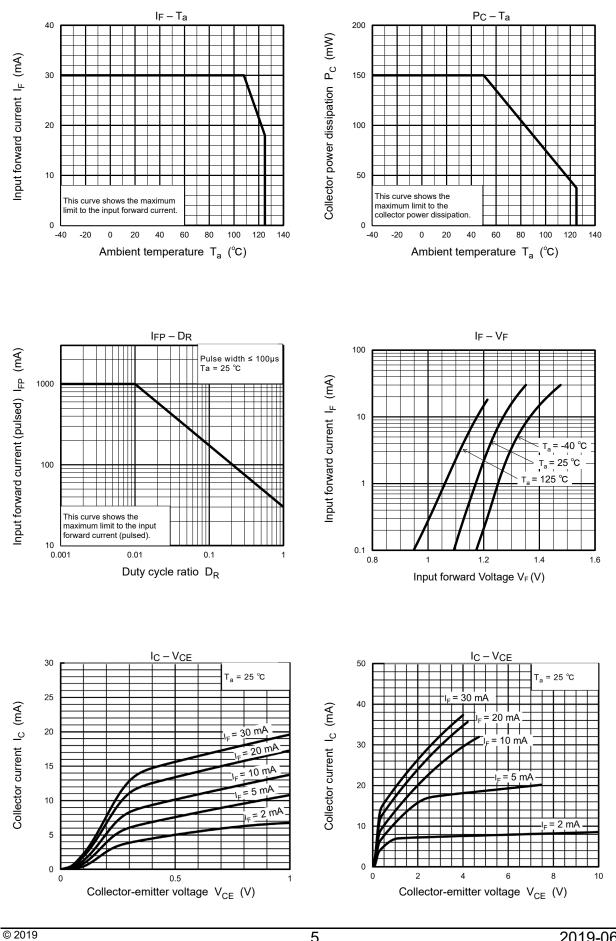
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	tr		_	3	_	
Fall time	t _f	V _{CC} = 10 V, I _C = 2 mA	_	5		μs
Turn-on time	t _{on}	R _L = 100Ω	_	5		
Turn-off time	t _{off}		_	5		
Turn-on time	ton		_	2		
Storage time	ts	$R_L = 1.9 k\Omega$ (Note 1) V _{CC} = 5 V, I _F = 16 mA	—	25	_	μS
Turn-off time	tOFF		_	45	_	

Note 1: Switching time test circuit

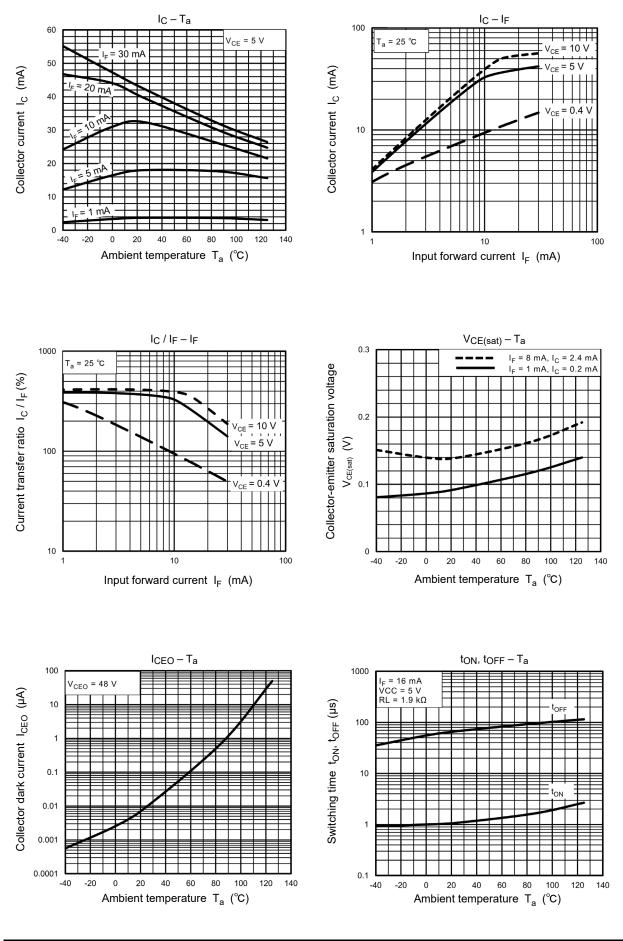


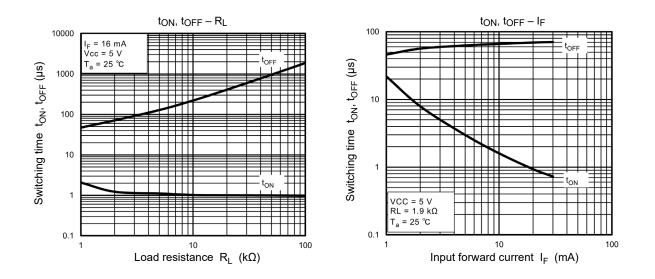


Characteristic Curves (Note)



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Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise specified.

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